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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/047,013	01/16/2002	Wolfgang Rosner	L&L-10232	5714	
24131	7590 04/22/2004		EXAM	EXAMINER	
LERNER AND GREENBERG, PA			ERDEM	ERDEM, FAZLI	
P O BOX 2480 HOLLYWOO	D, FL 33022-2480		ART UNIT	PAPER NUMBER	
,			2826		
			DATE MAILED: 04/22/200	4	

Please find below and/or attached an Office communication concerning this application or proceeding.

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	Application No.	Applicant(s)
	10/047,013	ROSNER ET A
Office Action Summary	Examiner	Art Unit
	Fazli Erdem	2826
The MAILING DATE of this communication apperiod for Reply	pears on the cover sheet with t	he correspondence address
A SHORTENED STATUTORY PERIOD FOR REPL THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1. after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a rep - If NO period for reply is specified above, the maximum statutory period - Failure to reply within the set or extended period for reply will, by statut Any reply received by the Office later than three months after the mailir earned patent term adjustment. See 37 CFR 1.704(b).	136(a). In no event, however, may a reply oly within the statutory minimum of thirty (30 will apply and will expire SIX (6) MONTHS te, cause the application to become ABAND	be timely filed O) days will be considered timely. From the mailing date of this communication. DONED (35 U.S.C. § 133).
Status		
1)⊠ Responsive to communication(s) filed on <u>03 F</u> 2a)⊠ This action is FINAL . 2b)□ This 3)□ Since this application is in condition for allowated accordance with the practice under the practice under the practice.	s action is non-final. ance except for formal matters	
Disposition of Claims		
4) Claim(s) 1-16 is/are pending in the application 4a) Of the above claim(s) 1-9 is/are withdrawn 5) Claim(s) is/are allowed. 6) Claim(s) 10-16 is/are rejected. 7) Claim(s) is/are objected to. 8) Claim(s) are subject to restriction and/o	n from consideration.	
Application Papers		•
9) The specification is objected to by the Examina 10) The drawing(s) filed on is/are: a) accomplicant may not request that any objection to the Replacement drawing sheet(s) including the correct 11) The oath or declaration is objected to by the Examination.	cepted or b) objected to by to drawing(s) be held in abeyance.	See 37 CFR 1.85(a). s objected to. See 37 CFR 1.121(d).
Priority under 35 U.S.C. § 119		
12) Acknowledgment is made of a claim for foreign a) All b) Some * c) None of: 1. Certified copies of the priority documen 2. Certified copies of the priority documen 3. Copies of the certified copies of the priority application from the International Burea * See the attached detailed Office action for a list	nts have been received. Its have been received in Applority documents have been recau (PCT Rule 17.2(a)).	ication No ceived in this National Stage
Attachment(s)		
1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08) Paper No(s)/Mail Date	Paper No(s)/M	mary (PTO-413) ail Date mal Patent Application (PTO-152)

Art Unit: 2826

DETAILED ACTION

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

- (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 1. Claims 10, 11, and 16 rejected under 35 U.S.C. 103(a) as being unpatentable over Forbes et al. (6,498,065) in view of Fitch et al. (5,554,870) further in view of Burns, Jr. et al. (6,077,745) further in view of Schafer et al. (DE 19632833).

Regarding Claims 10,11, and 16, Forbes et al. disclose a memory address decode array with vertical transistors where a decoder for a memory device is provided. The decoder array includes a number of address lines and a number of output lines. The address lines and the output lines form an array. A number of vertical transistors are selectively disposed at intersections of output lines and address lines. Each transistor is formed in at least one pillar of semiconductor material that extends outwardly from a working surface of a substrate. The vertical transistors each include source, drain, and body regions. A gate is also formed along at least one side of the at least one pillar and is coupled to one of the number of address lines. The transistors in the array implement a logic function that selects an output line responsive to an address provided to the address lines. Forbes et al. fail to disclose the required capping layer, insulators and the pillar in the required manner, and statistical mask structure. However, Fitch et al. disclose an integrated circuit having both vertical and horizontal devices and process for making the same where the required capping layer is disclosed. Furthermore, Burns, Jr. et al.

Art Unit: 2826

disclose a self-aligned diffused source vertical transistors with stack capacitors in a 4F-Square memory cell array where the required insulators and pillars in the required manner is disclosed. Finally, Schafer et al. disclose a cold cathode emitter manufacturing where the required statistical mask structure is disclosed.

It would have been obvious to one of having ordinary skill in the art at the time the invention was made to include the required capping layer, the insulator and pillar in the required manner and statistical mask structure in Forbes et al. as taught by Fitch et al., Burns, Jr. et al., and Schafer et al. respectively in order to have a vertical memory structure with better performance.

2. Claims 12 and 13 rejected under 35 U.S.C. 103(a) as being unpatentable over Forbes et al. (6,498,065) in view of Fitch et al. (5,554,870) further in view of Burns, Jr. et al. (6,077,745) further in view of Schafer et al. (DE 19632833) further in view of Forbes et al. (6,134,175).

Regarding Claims 12 and 13, Forbes et al., Fitch et al, Burns, Jr. et al., and Schafer et al. combination fail to disclose the required doping structure. However, Forbes et al. (6,134,175) disclose a memory address decode array with vertical transistors where the required doping structure is disclosed.

It would have been obvious to one of having ordinary skill in the art at the time the invention was made to include the required doping structure in Forbes et al. (6,498,065), Fitch et al., Burns, Jr. et al. and Schafer et al. as taught by Forbes et al. (6,134,175) in order to have a vertical memory structure with better performance.

Art Unit: 2826

3. Claim 14 rejected under 35 U.S.C. 103(a) as being unpatentable over Forbes et al. (6,498,065) in view of Fitch et al. (5,554,870) further in view of Burns, Jr. et al. (6,077,745) further in view of Schafer et al. (DE 19632833) further in view of Bertin et al. (6,060,746).

Regarding Claim 14, Forbes et al., Fitch et al., Burns, Jr. et al. and Schafer et al. combination fail to disclose the required tunnel structure. However, Bertin et al. disclose a power transistor having vertical FETs and method of making same where the required tunnel structure is disclosed.

It would have been obvious to one of having ordinary skill in the art at the time the invention was made to include the required tunnel structure in Forbes et al., Fitch et al., Burns, Jr. et al. and Schafer et al. as taught by Bertin et al. (6,060,746) in order to have a vertical memory structure with better performance.

4. Claim 15 rejected under 35 U.S.C. 103(a) as being unpatentable over Forbes et al. (6,498,065) in view of Fitch et al. (5,554,870) further in view of Burns, Jr. et al. (6,077,745) further in view of Schafer et al. (DE 19632833) further in view of Biegelsen et al. (5,607,876).

Regarding Claim 15, Forbes et al., Fitch et al., Burns, Jr. et al. and Schafer et al. combination fail to disclose the required core structure. However, Biegelsen et al.disclose a fabrication of quantum confinement semiconductor light-emitting device where the required core structure is disclosed.

It would have been obvious to one of having ordinary skill in the art at the time the invention was made to include the required core structure in Forbes et al., Fitch et al., Burns, Jr.

Art Unit: 2826

et al. and Schafer et al. as taught by Biegelsen et al. (5,607,876) in order to have a vertical memory structure with better performance.

Conclusion

Applicant's amendment necessitated the new ground(s) of rejection presented in this Office action. Accordingly, **THIS ACTION IS MADE FINAL**. See MPEP § 706.07(a). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the date of this final action.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Fazli Erdem whose telephone number is (571) 272-1914. The examiner can normally be reached on M - F 8:00 - 5:00.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Nathan Flynn can be reached on (571) 272-1915. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Art Unit: 2826

Page 6

Information regarding the status of an application may be obtained from the Patent

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may be obtained from either Private PAIR or Public PAIR. Status information for unpublished

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system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR

system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

FE

April 18, 2004

Minhloan Tran
Primary Examiner
Art Unit 2826